NSN 5962-01-480-7496

Memory Microcircuit - Page 1 of 1



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| Maximum Power Dissipation Rating: |
|---|
| 1.2 watts |
| Operating Tempurature Range: |
| -55.0/+125.0 degrees celsius |
| Storage Tempurature Range: |
| -65.0/+150.0 degrees celsius |
| End Application: |
| C141 awcfs gp |
| Features Provided: |
| Ultraviolet erasable and monolithic |
| Inclosure Configuration: |
| Dual-in-line |
| Output Logic Form: |
| Complementary-metal oxide-semiconductor logic |
| Input Circuit Pattern: |
| 22 input |
| Product Name: |
| Microcircuits, digital, memory, cmos, uv erasable-programming, logic array |
| Voltage Rating And Type Per Characteristic: |
| -0.5 volts power source and 7.0 volts power source |
| Time Rating Per Chacteristic: |
| 20.00 nanoseconds af output megawatts |
| Memory Device Type: |
| Pal |
| Special Features: |
| This item shall be made from an unprogrammed device in accordance with smd specifications 5962-8872404lx |
| Test Data Document: |
| 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). |
| Terminal Type And Quantity: |
| 24 printed circuit |
| Shelf Life: |
| N/a |
| Unit Of Measure: |
| |
| Demilitarization: |
| Yes - demil/mli |
| Fiig: |
| A458a0 |
| |